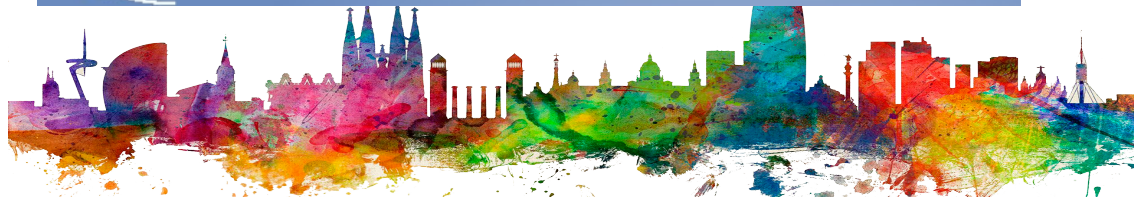




Laser & Photocathode study for e-gun

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1. Photocathodes today
Photocathodes in the future
2. Injector
 - Normal conducting
 - Superconducting
3. Various Parameters
 - Current,
 - Current density,
 - Frequency,
 - Operating temperatures,
 - Accelerating gradient
4. Conclusions

LITTERATURE

1. An Engineering Guide to Photo-injectors, T. Rao and D. H. Dowell, Eds.
2. SwissFEL cathode load-lock system:
https://www.researchgate.net/publication/281093830_SwissFEL_cathode_load-lock_system
3. Ultraviolet laser transverse profile shaping for improving x-ray free electron laser performance, S. Li, et al., PHYS. REV. ACC.&BEAMS 20, 080704 (2017)

Classification of the current Photocathodes

- **Electron emission**

- Photocathodes
 - » Metal
 - » Amorphous semiconductor
 - » Crystalline semiconductors

- **Electron acceleration**

- DC high voltage
- Radiofrequency acceleration
 - » Normal conductive acceleration
 - » Superconductive acceleration
- VHF field acceleration
 - » Normal conductive acceleration
 - » Superconductive acceleration

The gun photocathode preparation and exchange needs a **Load-Lock** system, as the cathode exchange takes **too time** without this.

The cathode surface gets contaminated in the atmosphere during installation, leading to **unpredictable quantum efficiency (QE) fluctuations**. This system leads to use of semiconductor cathodes like **Cs₂Te**

Types and Criteria of Photocathodes

Metals – low efficiency, good time response (prompt), resistant to contamination, need UV laser (Cu, Mg)

Semi-conductors – high efficiency, slower time response, sensitive to contamination, visible/IR lasers (GaAs, Cs₂Te, K₂CsSb, GaN)

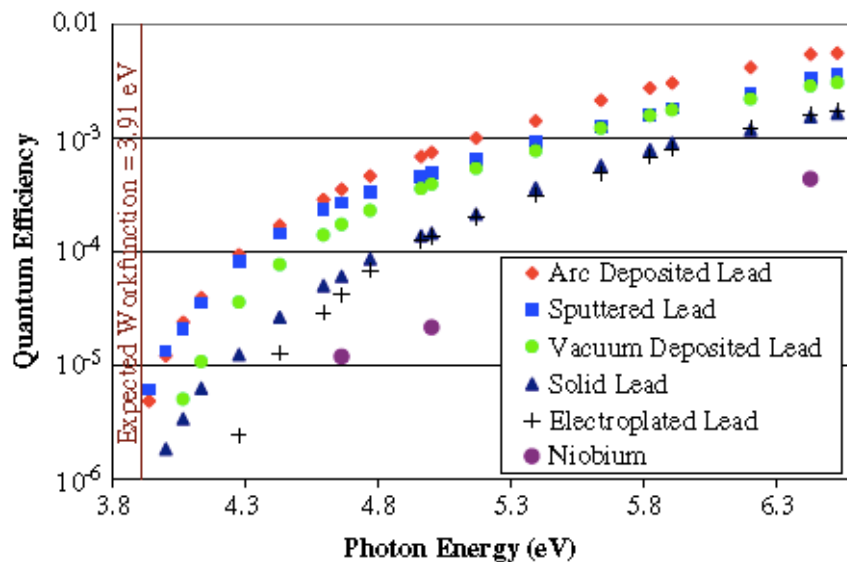
SELECTION CRITERIA

- High Quantum efficiency
- High Robustness
- Low intrinsic emittance
- Fast response time
- New ideas are welcomed!



- **Normal** conducting injectors
- **Room** temperature
- **Insensitivity** to contamination → easy handling
- **Longtime** operational lifetime, i.e. Mg, Cu are running for years
- **High work function**, ~1mA current :

UV laser for driving
High accelerating **gradient**
Very little **dark current**
QE quite low



QE of **Pb** deposited on **Nb** photo-cathodes.

The QE > 0.2% at 6.3 eV (196.3 nm) photon energy

It is proposed:

Mg → Normal conducting

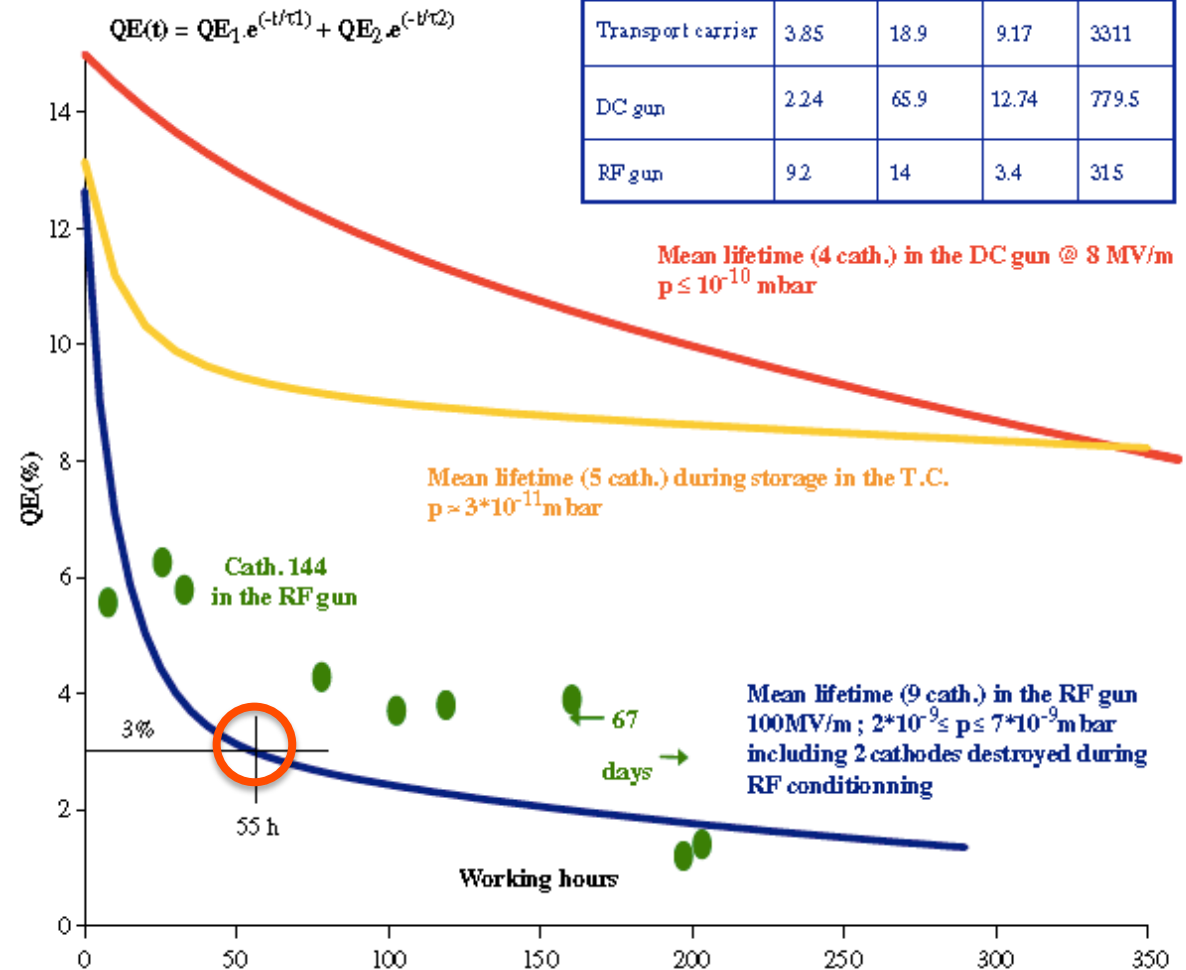
Pb/Nb → Super-conducting

Cs₂Te Photocathodes, 10% QE at 266nm

T. Rao et al. / Nuclear Instruments and Methods in Physics Research A 557 (2006) 124–130

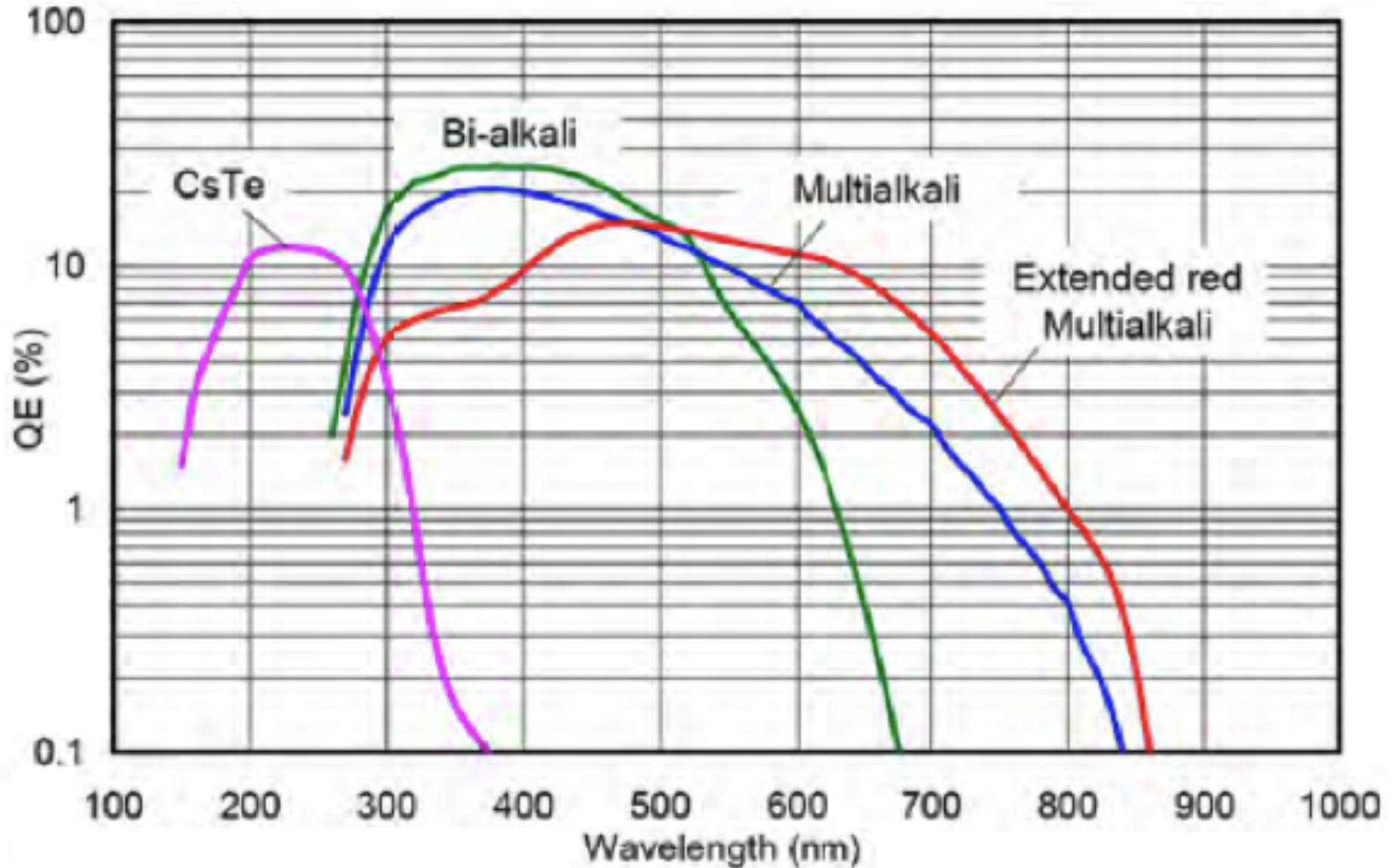
- High QE in UV
- NC RF-injector
- High Acc. Gradient
- 4 nC/pulse delivered, ~1mA current
- High work function → UV laser
- Sensitive to contaminants
- Quick QE decay from 12% to 3% in 55 h
- Load-lock system for cathode transfer/exchange
- Evaporation CsBr on Cs₂Te improves the lifetime

QE = f (t)	QE1 %	τ1 (h)	QE2 %	τ2 (h)
Transport carrier	3.85	18.9	9.17	3311
DC gun	2.24	65.9	12.74	779.5
RF gun	9.2	14	3.4	315





Cathode Wavelength	λ [nm] , E_{ph} [eV]	QE [%]		$E_a + E_{gap}$ [eV]	Thermal emittance $\left[\frac{\text{mm mrad}}{\text{mm rms}}\right]$	
					Theory (Equ. 7.6)	Experiment
Cs ₂ Te	262, 4.73	~10		3.5	0.9	1.2 ± 0.1
Cs ₃ Sb	532, 2.33	~4		1.6 + 0.45	0.42	0.56 ± 0.03
	473, 2.62	~7			0.62	0.66 ± 0.03
	405, 3.06	~9			0.82	0.80 ± 0.04
Na ₂ KSb	330, 3.76	~10		1 + 1	1.07	N/A
Na ₂ KSb:Cs	390, 3.18	~20		1 + 0.55	1.03	N/A
K ₂ CsSb	532, 2.33	~4		1 + 1.1	0.38	0.56 ± 0.03
	473, 2.62	~11			0.58	0.69 ± 0.03
	405, 3.06	~25			0.80	0.87 ± 0.04
GaAs(Cs,F)	532, 2.33	~10		1.4 ± 0.1	0.77	0.47 ± 0.03
GaN(Cs)	260, 4.77	~15		3.4 ± 0.1	0.94	1.35 ± 0.11





Class	Material	QE	Response time	Intrinsic Energy	Wave Length	Gun	Application
Normally conducting metals	Cu, Mg	10^{-5} - 10^{-4}	10's fs	100's mV – 1's V	UV	NC-RF, VHF	Low rep rate FELs
Super conducting metals	Nb, Pb	10^{-5} - 10^{-4}	10's fs	100's mV – 1's V	UV	SC-RF	High rep rate FELs
Positive e ⁻ affinity Te-based	Cs ₂ Te	0.1-0.2	ps's	100's mV	UV	NC-RF, SC-RF, VHF, DC	High rep rate FELs
Positive e ⁻ affinity Sb-based	Cs ₃ Sb etc	0.1-0.2	ps's	100's mV	Visible	DC, VHF, SCRF(?), NCRF(???)	ERLs, High rep rate FELs
Negative e ⁻ affinity semiconductor	GaAs, etc	0.1-0.35	1 – 100 ps	10's mV – 100's mV	IR- Visible	DC (XHV)	Polarized sources, ERLs



The **laser** system for the photo-injector is selected based on the **cathode material** and the **electron beam parameters** required for the application

The **temporal** and **transverse shape** of the laser pulse, together with the **quantum efficiency (QE)** of the photocathode surface, determines the temporal and transverse distribution of the electron beam upon emission; having a significant impact on beam brightness and FEL performance

Metal photocathodes require **UV photons** due to their high work function, therefore eliminating the use of liquid crystal SLMs (= Spatial Light Modulator) directly in this wavelength range

Host	Dopant	Wavelength [μm]	Band Width [nm]	Gain Cross Section [×10 ⁻²⁰ cm ²]	Upper State Lifetime [μs]
YAG	Nd	1.064	0.6	33	230
YLF	Nd	1.047-1.0530	1.2	18	480
Vanadate	Nd		0.8	300	100
Phosphate Glass	Nd	1.0535-1.054	24.3	4.5	323
KGW	Yb	1.026	25	2.8	250
YAG	Yb	1.030	6.3	2.0	950
Phosphate Glass	Yb	1.06-1.12	62	0.049	1 300
Sapphire	Ti	0.790	230	41	3.2

MAXIV laser→
Ti:Sapphire
with specifications



Central wavelength	790 nm
Pulse duration	50 fs
Pulse energy	7.5 mJ
Repetition rate	1 kHz



The following parameters to be defined with codes ASTRA and DYNAC:

- ✓ The electron emission affection by the electron **beam space charge field**:

$$E_{SCL} = \frac{q}{A\epsilon_0} = \frac{\sigma}{\epsilon_0}$$

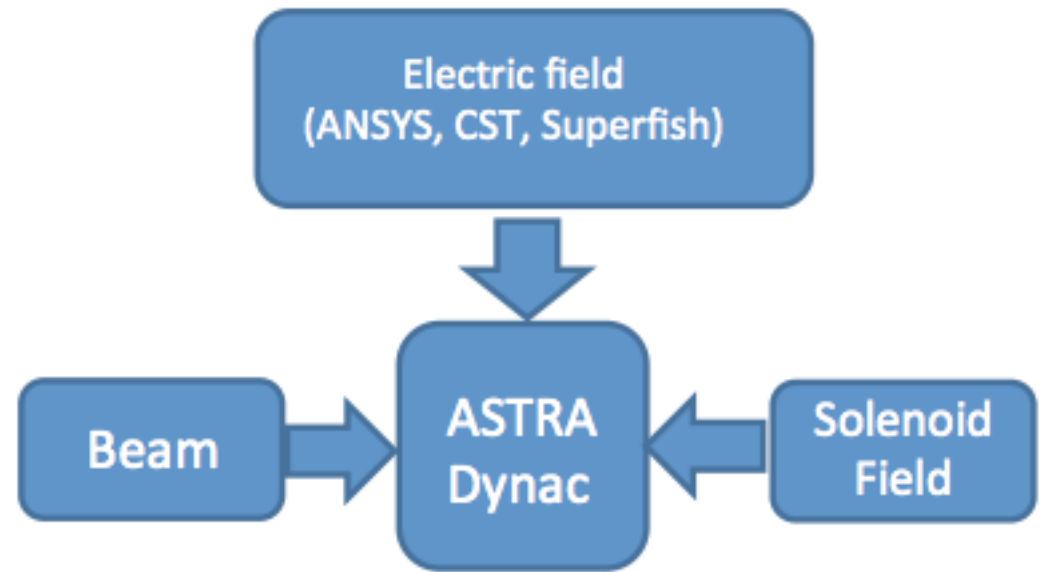
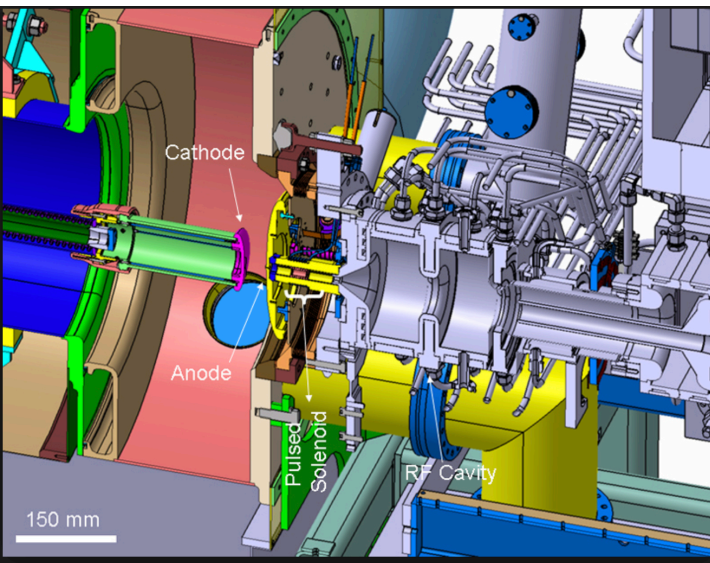
- ✓ The 2-D sub-spaces of xx' , yy' and zz' , the **trace spaces**,
- ✓ The **energy** normalized trace space emittance:

$$\epsilon_n = \beta\gamma \sqrt{\langle x^2 \rangle \langle x'^2 \rangle - \langle xx' \rangle^2}$$

- ✓ The **peak current**, I_{peak} , as the bunch charge divided by the bunch length, at the FWHF of the bunch length
- ✓ The transverse normalized **beam brightness** combining the emittance and the peak current:

$$B_n = \frac{2I}{\pi^2 \epsilon_{n,x} \epsilon_{n,y}}$$

e-gun Simulation & Strategy for INFN/SWISS FEL

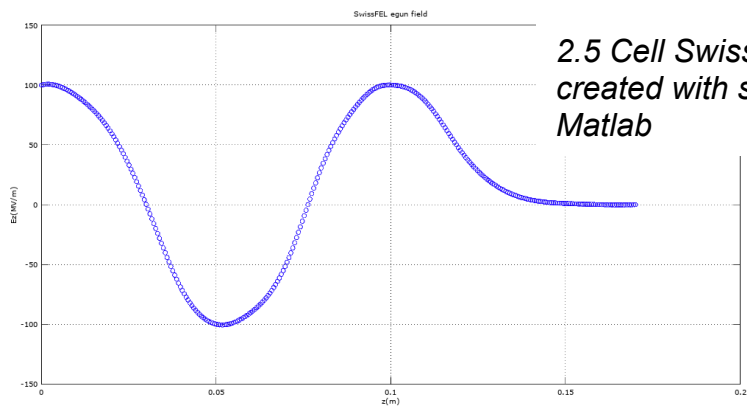


Material:

Beams: INFN Beam, SwissFEL Beam (NTUA team)

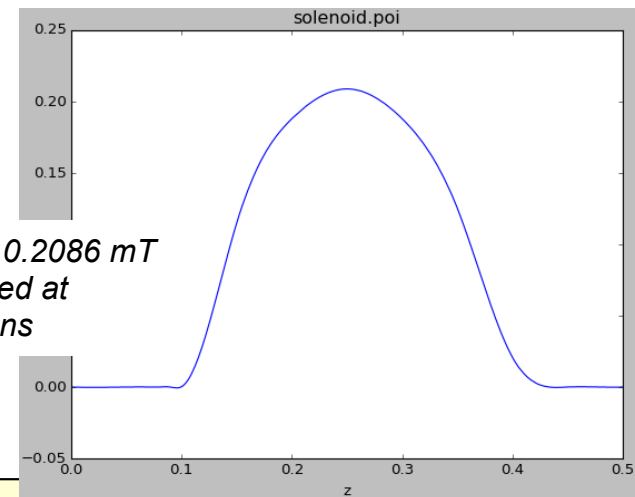
Electric Fields: 1.5 cells (INFN), 2.5 cells (SwissFEL) created with Matlab

Solenoids: INFN, SwissFEL created with Matlab



*2.5 Cell SwissFEL Gun Electric field
created with spline interpolation on
Matlab*

*Different Solenoids with peaks at 0.2086 mT
like SwissFEL gun solenoid created at
Matlab and used for the simulations*



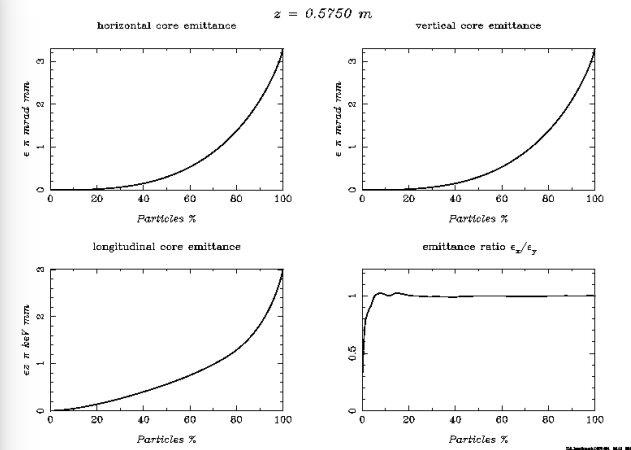
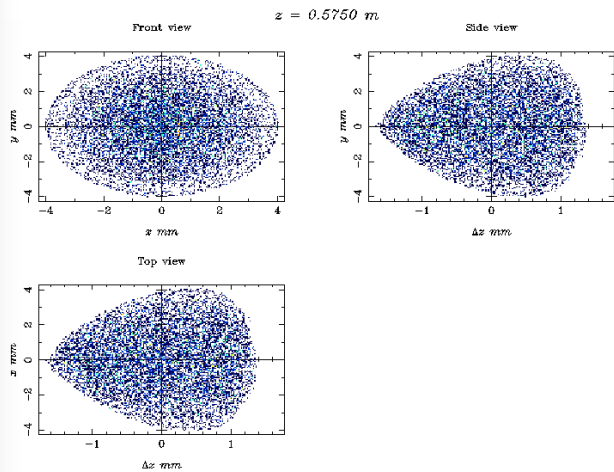
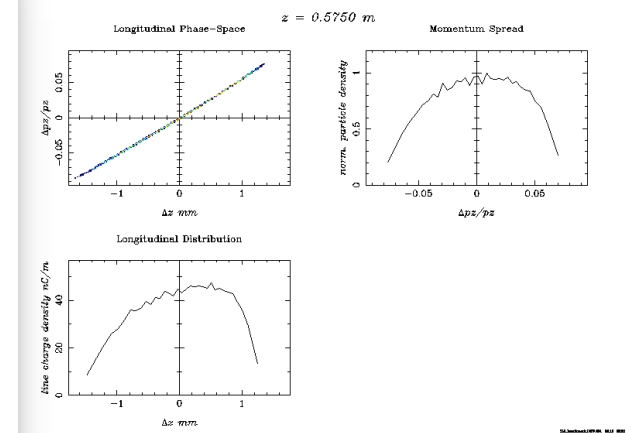
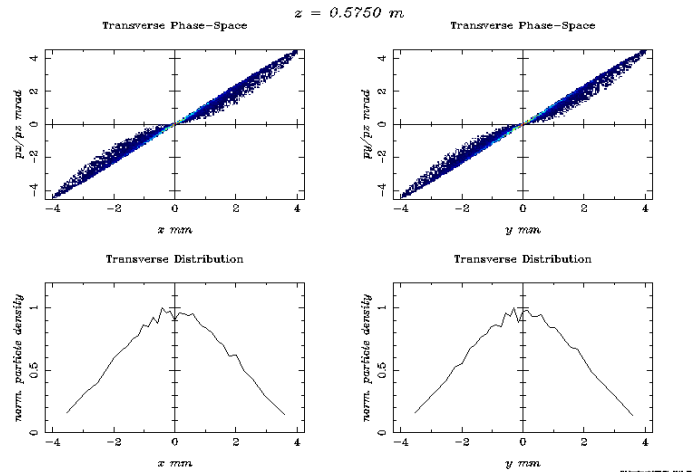
Preliminary simulating data by ASTRA

Scenario I : INFN Beam , 1.5 cell, INFN Solenoid

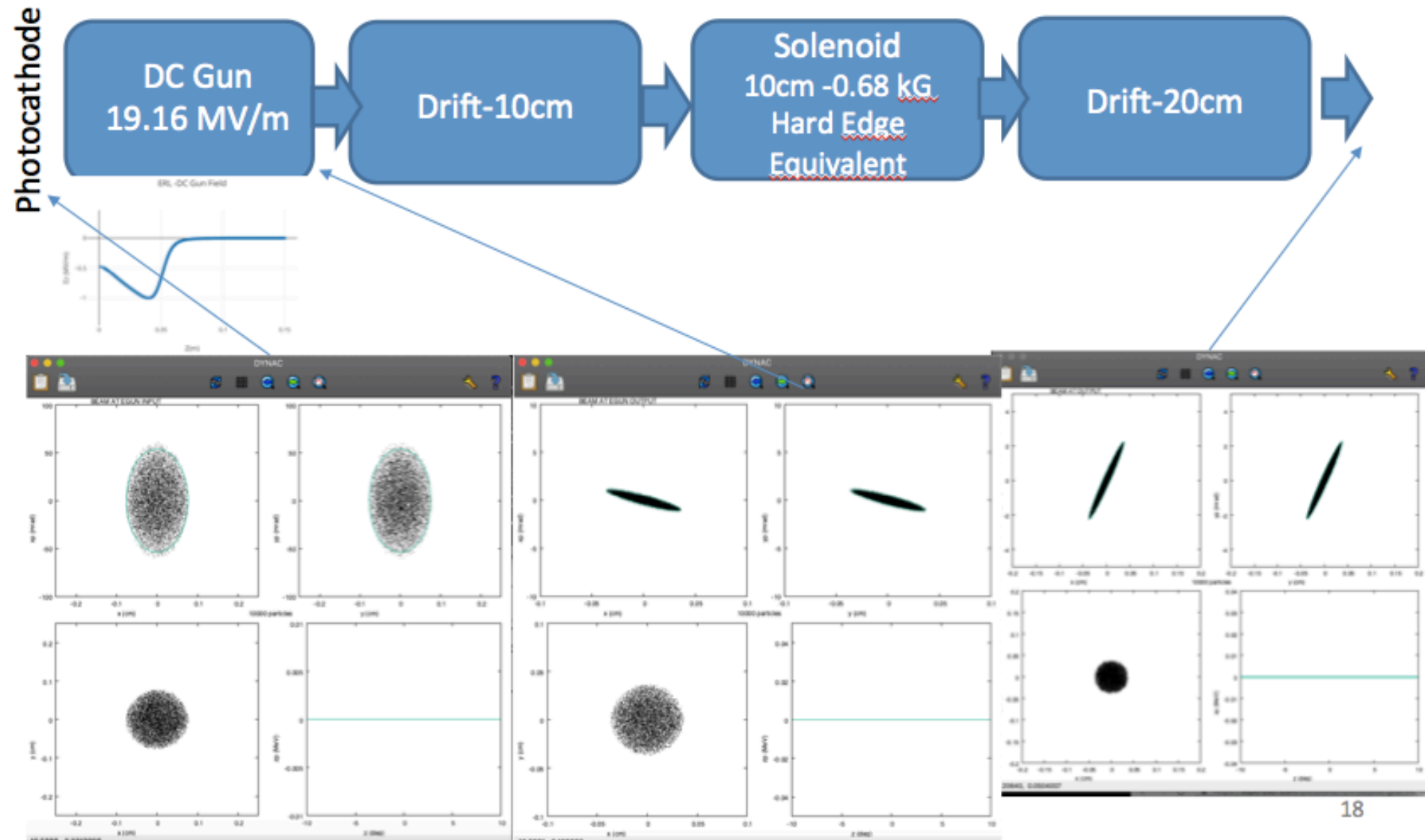
Scenario II: INFN BEAM, 2.5 Cell- SwissFEL , INFN solenoid

Scenario III: INFN Beam- 2.5 cell RF gun SwissFEL , created solenoid

Scenario IV- INFN Beam, 2.5 Cell RF gun SwissFEL – created solenoid shifted 0.1m



Preliminary simulating data by DYNAC for ERL DC gun





- Various **modes** and **types** of the photocathodes have been investigated
- The choice of the photocathode is **dictated** by the requirements on the **average current** and by the **available laser**
- Reliable cathode and laser systems exist for average current of **10 mA**
- The current can be increased to **100 mA**, by a small improvement in both the cathode and the laser system
- The limited lifetime of the cathodes is an **IMPORTANT** issue
- An important study of the **the degradation** of the cathode performance, so to improve **the lifetime** of these cathodes at least by an order of magnitude is necessary
- A very very preliminary proposal could be :

a cathode Cs_2Te , with **QE ~0.1-0.2 %**, **UV**, **SC/NC-RF**, **High repetition rate**;
by a **UV laser**

But ... More study is needed for final selection



- ASTRA and DYNAC codes were investigated for simulation of the beam after the Photocathode.
- Preliminary results were presented
- Simulation methodology and strategy have been established



The IASA-NTUA-ESS team will work to:

- **Simulations** with respect to proposed topologies for:
 - ✓ Electron generation by laser
 - ✓ Beams from photocathode and perform structure optimization
- **Mechanical designs** of the photocathode, RF cavity and Solenoids



Thank you!

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